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Transition metal dichalcogenide-decorated MXenes: promising hybrid electrodes for energy storage and conversion applications

N. R. Hemanth, ^{†a} Taekyung Kim, ^{†b} Byeongyoon Kim, ^{†b} Arvind H. Jadhav, ^c Kwangyeol Lee ^{*b} and Nitin K. Chaudhari ^{*d}

Various two-dimensional (2D) materials have demonstrated unique structure-dependent characteristics that are conducive to energy-harvesting applications. Among them, the family of layered MXenes has found a wide range of applications in batteries, supercapacitors, photo- and electrocatalysis, water purification, biosensors, electromagnetic interference shielding, structural composites, etc., owing to their well-defined structure, large surface area, large interlayer distance, and excellent thermal and electrical conductivity. However, layer restacking due to hydrogen bonding or van der Waals forces between the layers considerably impedes the utility of MXenes. To tackle the restacking issues, transition metal dichalcogenides (TMDs) such as MoS₂, WS₂, and MoSe₂ nanosheets have been uniformly dispersed on the surface of MXenes, which not only mitigates the restacking of the MXenes but also improves the electrochemical performance due to the synergistic interaction between MXenes and TMDs. This review describes recent advances in the synthesis of MXene/TMD heterostructures and the nature of the synergistic interactions between TMDs and MXenes in energy-related applications. We further highlight future research directions for MXene/TMD-based materials for energy storage applications.

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^a Department of Metallurgical and Materials Engineering, National Institute of Technology Karnataka (NITK), Surathkal, Karnataka 575025, India^b Department of Chemistry and Research Institute for Natural Sciences, Korea University, Seoul, 02841, Republic of Korea. E-mail: kylee1@korea.ac.kr^c Centre for Nano and Material Science (CNMS), Jain University, Jain Global Campus, Bangalore 562112, Karnataka, India^d Department of Chemistry, School of Technology, Pandit Deendayal Petroleum University, Gandhinagar 382007, Gujarat, India. E-mail: nitin.chaudhari@sot.pdpu.ac.in

† These authors contributed equally to this work.



N. R. Hemanth

N. R. Hemanth is a final year undergraduate student pursuing a bachelor's degree in metallurgical and materials engineering, at National Institute of Technology Karnataka, Surathkal, India. His research interests include 2D-based nanomaterials, functional polymeric materials and composites for specialized industrial applications. His other research interests include nanomaterials for energy harvesting applications.



Taekyung Kim

Dr Taekyung Kim earned his PhD degree (2020) in inorganic chemistry from Korea University after working at Kolon Industries, Inc., (Republic of Korea) as an engineer for several years. Currently, his research interests are mainly focused on the development of synthetic methods for phase and structure-controlled nanocatalysts and their potential applications in electrocatalytic water splitting.

1. Introduction

Energy and environmental issues have reached crisis levels over the last decade due to the rapid depletion of fossil fuels and the associated climate changes.¹ To address these challenges, it is imperative to develop sustainable energy production technologies by tapping into renewable energy sources such as solar, geothermal, and wind energy. The development of electrochemical storage devices such as batteries, supercapacitors, and water electrolyzers for converting hydrogen to electrical energy, as well as fuel cells for efficient conversion of chemical energy in hydrogen to electricity, is critical.²

In recent years, atomically thin two-dimensional (2D) materials have attracted considerable interest owing to their unmatched portfolio of optical, electrical, and mechanical properties.³ Among the plethora of 2D materials, transition metal carbides/nitrides (MXenes), the newest additions to the family of 2D materials, have

been prepared by the selective extraction of element 'A' from layered hexagonal MAX precursors using hydrogen fluoride as an etching agent, or from layered ceramics.⁴ The large surface area, tunable interlayer distance, and narrow diffusion barrier, combined with the superior metallic conductivity of MXenes, make them optimal electrode materials.⁵ However, MXene layers undergo restacking, which limits their potential utility in electrochemical applications.⁶ Therefore, for further enhancement of the electrochemical performance, spacers have been introduced between the layers of MXenes to develop a porous structure. The introduction of nano-carbon, conductive polymers, heteroatoms, metal oxides, and TMDs considerably increased the interlayer distance to yield better electrochemical performance.⁷ On the other hand, transition metal dichalcogenides (TMDs) have been extensively explored as electrode materials in the past decade due to their large specific area, excellent electrical properties, atomically thin layered arrangement,



Byeongyoon Kim

Dr Byeongyoon Kim received his PhD Degree (2018) in inorganic chemistry from Korea University, Republic of Korea. Currently, he is working as a postdoctoral fellow with Prof. Kwangyeol Lee at Nano Chemistry Laboratory, Korea University. His research interests include the design and synthetic methodology for transition metal-based functional nanomaterials and the applications of electrocatalysis.



Arvind H. Jadhav

Dr Arvind H. Jadhav is currently working as an Assistant Professor at the Centre for Nano and Material Sciences (CNMS), JAIN University, India. He received his PhD from Myongji University, Republic of Korea. Dr Jadhav has several research publications to his credit in reputed peer reviewed international journals. He is also a recipient of many awards for his academic excellence with a gold medal for his PhD research and a good number of best paper and best poster presentation awards. His research areas focus on heterogeneous catalysis for CO₂ conversion and utilisation, synthesis of ILs for organic transformations, and sustainable energy applications.



Kwangyeol Lee

Professor Kwangyeol Lee obtained his PhD degree (1997) in chemistry from the University of Illinois at Urbana-Champaign. After fulfilling his military obligation, he joined Korea University in 2003 as a chemistry faculty member, before being appointed as a professor. He is the recipient of the 2009 Wiley-KCS Young Scholar Award. His current interests include the development of synthetic methodologies for nanoscale materials, the application of nanomaterials in

biomedical fields, and the development of nanotechnologies to support the environment by creating sustainable energy sources.



Nitin K. Chaudhari

Dr Nitin Chaudhari is an Associate Professor at Pandit Deendayal Petroleum University, Gandhinagar, India. He received his PhD degree in materials science from Korea University, South Korea in 2013. He subsequently worked as a research professor at Myongji University and Korea University, South Korea from 2013 to 2019. Later, he joined Nexcoms Ltd. Co., South Korea as Deputy Director before moving to India. His research interest includes the design and development of active electrode materials such as porous carbons, nanocomposites, oxides, sulphides, hydroxides, 2D MXenes, and nanomaterials for energy storage and conversion devices.

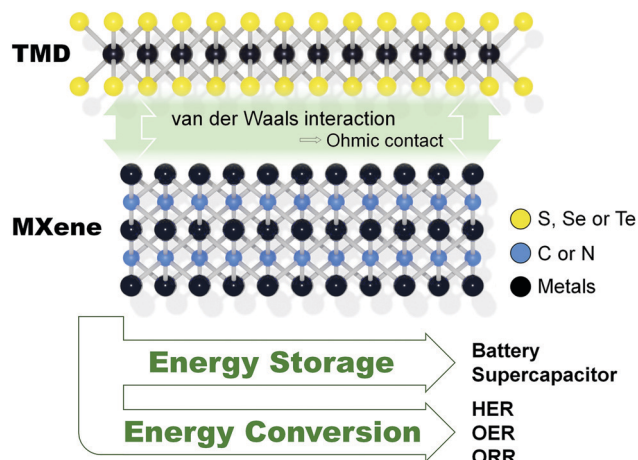


Fig. 1 A graphical abstract of the 2D TMD/MXene hybrid structure toward energy storage and conversion.

and stability.⁸ However, TMDs suffer from poor cycling stability, low electrical conductivity, and, most critically, a limited number of active sites located on the edges, which seriously limits the catalytic performance of TMDs.⁹ Recent studies show that combining the 2D structures of MXenes and TMDs can preserve the best features of both the MXenes and TMDs. When MXenes are combined with TMDs, restacking of the layers is hindered, thereby increasing the contact area between the electrolyte and electrode.^{7a,10} Moreover, the 2D heterointerface between MXenes and TMDs consists of van der Waals interactions that can prevent Fermi level pinning; this effect operates synergistically with the work function adjustability of metallic MXenes to afford Schottky barrier-free contact and reduce the contact resistance.¹¹ The MXene–TMD composites demonstrated excellent reversible specific capacitance, superior coulombic efficiency, and improved cyclability and rate performance in electrochemical applications (Fig. 1).

An extensive literature survey reveals the existence of several review papers on the respective topics concerning MXenes and TMDs.^{4c,8,12} However, no critical review article on MXene/TMD composites is available, although this unique heterostructure family has great potential as electrochemical materials; thus, a timely account of this topic would be greatly helpful to researchers in related fields. The present review highlights the recent developments in the fabrication and electrochemical applications of MXene/TMD composites. Furthermore, the electronic structure and ion transfer mechanism are explained using density functional theory (DFT). Finally, we summarize the present research on MXene composites to provide overall prospects for this material family and trigger rapid development in this exciting material class for future energy applications.

2. MXenes and TMDs

2.1 Transition metal carbides/nitrides (MXenes)

2.1.1 Synthesis. Two-dimensional transition metal carbides or nitrides, referred to as MXenes, are an emerging family of metallic or semiconducting materials possessing electrical

conductivity and a hydrophilic surface.¹³ They are usually represented by the formula $M_{n+1}X_nT_x$ ($n = 1, 2$ or 3), where M refers to an early transition metal ($M = \text{Sc, Ti, V, Cr, Zr, Nb, Mo, Hf, and Ta}$), X denotes carbon or nitrogen, and T stands for surface terminal groups ($T = \text{OH}^-, \text{F}^-, \text{and } \text{O}^{2-}$).¹⁴ MXenes are synthesized by the selective removal of the A-group (mostly elements of IIIA and IVA groups of the periodic table) from layered hexagonal ternary carbides known as MAX phases (Fig. 2).¹⁵ MAX powders are immersed in a controlled quantity of hydrofluoric acid (HF) solution at room temperature or higher temperature, resulting in the formation of surface terminals on MXenes, which are mainly oxygen and/or hydroxyl moieties.¹⁶ Since the direct handling of HF is dangerous due to its toxic nature, a safer *in situ* formation of HF has been accomplished through the reaction of HCl and fluoride salts or *via* ammonium bifluoride. These HF precursors aid in the simultaneous intercalation of cations like $\text{Li}^+, \text{Na}^+, \text{K}^+, \text{NH}_4^+, \text{Ca}^+, \text{and } \text{Al}^{3+}$ between the interlayers.^{15,17} The intercalation of the cation and water during this process results in delamination without any additional steps, which is another advantage of *in situ* HF over the pure HF etching method. The etching conditions for the complete transition of MAX to MXene depend on different variables; the M–Al bond strength in Al-based MAX phases determines the etching environment, and the increasing number n in $M_{n+1}C_nT_x$ type requires stronger and/or longer etching conditions. On the other hand, nitride-based MXenes have been prepared using molten fluoride salts for etching the A-elements from MAX precursors at a relatively higher temperature (at 550 °C) under argon atmosphere.^{4c,18} Synthesis of MXenes by chemical vapor deposition (CVD) is also possible, where high-quality ultra-thin orthorhombic $\alpha\text{-Mo}_2\text{C}$ crystals with a lateral size of $\sim 100 \mu\text{m}$ were produced from the decomposition of methane on a bilayer substrate comprising copper foil placed over molybdenum foil. This method was further applied to the fabrication of WC and TaC crystals.¹⁹ Until now, various bottom-up synthesis methods such as CVD, template methods, plasma-enhanced pulsed laser deposition, *etc.*, have been reported to produce higher quality crystals compared to selective etching processes.²⁰ While ultra-thin MXenes have been obtained by bottom-up synthesis, single-layered MXenes have not yet been demonstrated by these processes. MXenes can also be prepared from non-MAX phase precursors by etching the Al–C units from $M_n\text{Al}_3\text{C}_2$ and $M_n\text{Al}_4\text{C}_{n+3}$.²¹ Furthermore, it has been reported that etching of Al–C units together is energetically more favorable than etching of single Al units. Delamination of MXenes is a crucial step to the understanding of their fundamental properties, and is also necessary for the fabrication of MXene-based electrodes with high storage capacity.^{21a} Before delamination, the structure of multilayered MXenes is similar to that of graphene-like stacks of sheets, and delamination of multilayered MXenes into few-layered or mono-layered nanosheets using an organic base drastically improves the accessibility to the surface.²² Due to strong interlayer forces, delamination of multilayered MXenes by mechanical exfoliation is more difficult than those of graphite and MoS_2 , and results in poor yield of mono-layers of MXenes.²³ Therefore, delaminating by intercalation of various organic,

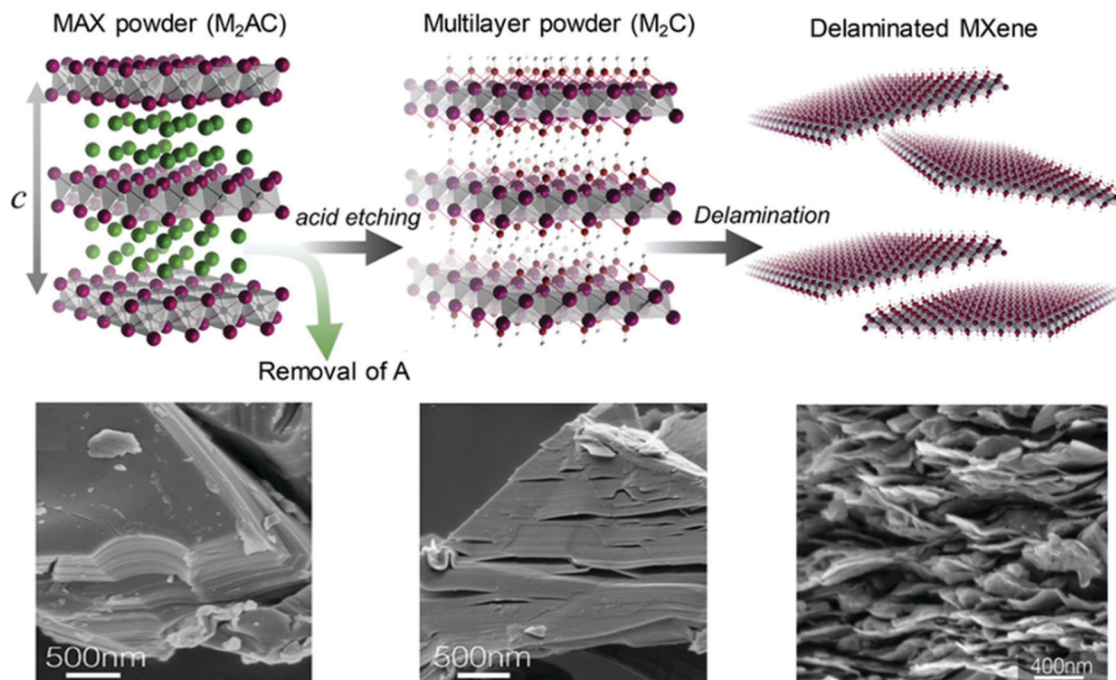


Fig. 2 Typical synthesis of MXene from MAX phase via the selective etching method and its delaminated structure; the bottom SEM images represent MAX, MXene and delaminated-MXene structures, respectively. Reproduced with permission.¹¹³ Copyright 2020, Wiley.

inorganic, and ionic species followed by sonication has been widely practiced, because of large-scale production of single MXene layers.^{16,22a,22b}

2.1.2 Structure and properties. The MXene crystal structure is similar to that of the parent MAX phases; the mono-layer of MXene comprises a hexagonal lattice with six-fold symmetry, wherein the transition metal ions are six-coordinate.²⁴ The remarkable properties of MXenes include excellent thermal and electrical conductivity, a high Young's modulus, and a tunable bandgap.²⁵ The surface termination is an important factor in determining the mechanical properties of MXenes. For example, a recent study has revealed that the O-terminated MXenes display better mechanical strength, mainly due to the stronger bonding between M–O than M–F and M–OH.²⁶ Thin MXene films are transparent and conduct electricity, and this unique combination of properties makes them novel materials for transparent conductive electrodes as well.²⁷ However, the synthesis process and composition can affect the electronic conductivity of MXene; larger flakes with minimum defects have displayed higher conductivity. Furthermore, high-quality single flakes and O/OH-terminated MXenes are more stable towards oxidation. Pristine MXenes display metallic character, but their metallic nature decreases as the number of layers increases. In addition, a few MXene materials become semiconducting after surface modification.²⁸ MXenes are unique among two-dimensional materials, including graphene, because of their notable hydrophilic surface and exceptional metallic conductivity.²⁹ Density functional theory predicts that the pristine MXene would exhibit magnetic behavior due to the presence of Ti atoms on the surface. With the surface termination step, the MXene loses its magnetic property.³⁰

The appealing properties of MXenes lead to a wide range of applications, including chemical adsorption, electromagnetic interference (EMI) shielding, biomedical applications, wastewater treatment, and environmental remediation.^{13,31} MXenes have shown great potential as electro/photocatalysts for hydrogen evolution reactions, and CO₂ reduction reactions, and as electrode materials for supercapacitors and batteries.³² However, the low capacitance of the resulting anodes, complex surface functionalities, and oxidation of MXenes limit their applications.^{4b,7a,33}

2.2 Transition metal dichalcogenides (TMDs)

2.2.1 Synthesis. Two-dimensional transition metal dichalcogenides are intriguing semiconducting layered materials with the typical formula MX₂, where M denotes a transition metal atom of group VI of the periodic table (*e.g.*, Mo or W), whereas X is a chalcogen atom (S, Se, or Te).^{8b} Mechanical exfoliation, in which a layer is peeled off from the bulk crystals using adhesive Scotch tape, is a clean and rapid method for producing high-quality crystalline and atomically thin mono-layers of TMDs. However, this method produces a non-uniform flake size, the deposited material is non-uniform, and it is difficult to separate the layers.³⁴ To overcome these problems, nanolayers of bulk TMD crystals are produced by liquid-phase exfoliation by ultrasonication in organic solvents, in which the nanolayers remain chemically unaltered, and their electronic properties are maintained.³⁵ Recently, aqueous ammonia has been used as an alternative and eco-friendly solvent for scalable liquid-phase exfoliation of MoS₂ and WS₂.³⁶ Furthermore, this solvent offers high concentration yields with good stoichiometry, structural

and semiconductor qualities, and does not require additional surfactants and stabilizers. High-quality ultra-thin TMDs can also be prepared from a molecular beam epitaxy (MBE) method in an ultrahigh vacuum chamber with high purity source materials (Fig. 3a).³⁷ The low growth temperature, low deposition rate, and *in situ* characterization during the MBE process provide good synthetic control with minimal impurities in the final TMD films. Bottom-up synthesis routes are the most practical approaches to 2D TMDs because they afford a high yield, precise control over the lateral size, and a homogeneous composition and structure of the nanolayers.^{8b} Chemical vapor deposition is widely considered as a scalable method of developing thin 2D TMDs and their heterostructures (Fig. 3b), due to the great control over the morphology and low cost. As a result, several MX_2 type TMDs with excellent semiconducting properties have been synthesized. The earliest and primary method reported employs the vapor-phase reaction of the parent metal oxide (WO_3 , or MoO_3) and chalcogen element at high temperature by co-evaporation, leading to the growth of thin stable TMDs on the substrate.³⁸ In addition to various growth parameters of CVD such as temperature, growth time, and atomic gas flux, growth substrate and system design are also important for controlled and optimized growth of 2D TMDs.³⁹ Furthermore, by increasing the density of edge sites during the mid-growth process and by creating vacancies to activate the

basal plane in the post-growth process, the catalytic activity of CVD-grown TMDs can be enhanced.⁴⁰ Another CVD growth occurs *via* a two-step process, where the pre-deposited metal precursor on the substrate reacts with a gaseous vapor of sulfur, selenium, or tellurium in an inert atmosphere.⁴¹ Synthesis of large-area, thin, crystalline TMDs on various insulating substrates has been accomplished by the thermolysis process, in which the crystallinity increases sharply upon the addition of sulfur during high-temperature annealing of thermally decomposed salts.⁴² Better control might be achieved by metal-organic chemical vapor deposition (MOCVD), in which metal-organic or organosulfur precursors are used to develop wafer-scale films with high crystallinity (Fig. 3c). Precise control over the gas-phase precursors helps in tuning the domain size, shape, and nucleation density. However, the noxious precursors and slow deposition are the main drawbacks of this process.⁴³ Recently a novel growth-etch MOCVD process has been presented to eliminate the carbon contamination and small domain size resulting from the conventional MOCVD process, wherein introducing water vapor during the process has improved the final crystal quality.⁴⁴ Atomic layer deposition by a gas-phase reaction of the parent elements has recently been used to prepare conformal, thin, binary transition metal sulfides on various substrates, including 3D templates.⁴⁵ The uniform, area selective growth of 2D thin TMD films has been achieved by controlling the incubation period on various substrates or by using the ABC-type plasma-enhanced ALD process.⁴⁶

2.2.2 Structure and properties. The crystal structure of single-layer TMDs (MX_2) comprises a transition metal layer (M) sandwiched between two atomic layers of chalcogen (X).⁴⁷ A triangular prismatic phase (2H) and an octahedral phase (1T) are the two commonly observed phases. The thermodynamically stable 2H- MoS_2 exhibits six-siemens atoms prismatically surrounding each of the Mo atoms, and the metastable 1T- MoS_2 comprises six-siemens atoms surrounding each of the Mo atoms in the form of a distorted octahedron.⁴⁸ Each of these phases exhibits distinctively different electronic properties, as 2H- MoS_2 is semiconducting, whereas 1T- MoS_2 is a metallic and more active hydrogen evolution catalyst.

The Young's modulus of defect-free single-layer MoS_2 is comparable to that of stainless steel, and therefore monolayer MoS_2 can be used as a reinforcing component in composite materials.⁴⁹ The unique functionalities of 2D TMDs allow them to transform the indirect bandgap in multilayered TMDs to a direct bandgap in single-layered TMDs with good carrier mobility.⁵⁰ The unique properties of TMDs have led to many phenomenal applications. The tunable bandwidth of monolayer TMDs has been extensively utilized in the field of high-performance flexible electronics and optoelectronics.⁵¹ The inactive basal plane in MoS_2 (typical TMD) impedes the trapping of Li^+ on the surface, and thus the coulombic efficiency of MoS_2 anodes is far superior to that of graphene oxide and its derivatives.^{9a} The desirable characteristics of high capacitance and stability have also been observed in other TMDs, which has led to widespread interest and advances in the domain of energy storage and conversion.⁵² The morphologies of 2D TMDs, thermal stability, conductivity, mechanical features, tunable bandgap, and their direct influence

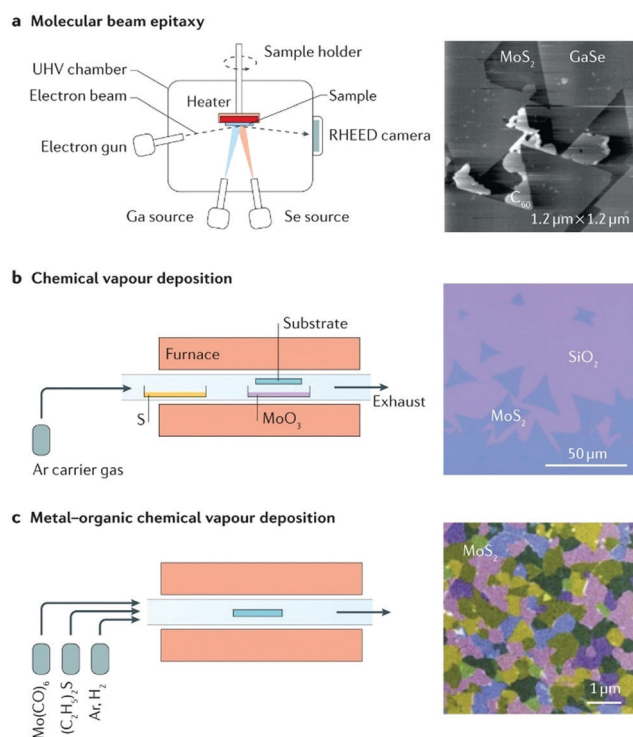


Fig. 3 (a) Schematic illustration of a molecular beam epitaxy process with atomic force microscopy image of GaSe mono-layer grown on MoS_2 . (b) Schematic illustration of chemical vapour deposition with an optical image of MoS_2 domains grown on SiO_2 . (c) Schematic illustration of metal-organic chemical vapour deposition with a false-colour dark field transmission electron microscopy image of the MoS_2 mono-layer having different grain orientation. (a), (b) and (c) Reproduced with permission.^{8b} Copyright 2017, Macmillan Publishers Limited.

on the optical properties of materials have inspired a broad range of applications in sensors,⁵³ catalysis for hydrogen evolution,⁵⁴ flexible electronics and optoelectronics,^{51,55} and energy storage.⁵⁶ However, developing routes for the synthesis of structures with more active sites in the basal plane remains a significant challenge. Furthermore, the electrochemical stability and electrical conductivity are far from satisfactory.

On the other hand, coupling TMDs with MXenes reportedly allows the full exploitation of the extraordinary features of each component. The TMD/MXene heterostructure demonstrated outstanding specific capacitance, durable performance, enhanced coulombic efficiency, satisfactory reverse capacitance at high current rates, and enhanced ion transport and structural stability during redox reactions.⁵⁷

3. Synergy between MXene and TMDs

When combining two different materials to obtain a heterostructure, synergetic interaction between the different material phases is generally expected. Although the effort to combine TMDs and MXenes is in the very early stage, synergistic interaction between these materials has been demonstrated in a number of examples.⁵⁸ When a junction is formed by a metal and semiconductor contact, it creates a potential barrier for charge carriers to cross the junction, the so-called Schottky barrier (SB), which ideally follows the predictions of the Schottky–Mott model:

$$\Phi_{B,n} = \phi_M - \chi_S, \Phi_{B,p} = I_S - \phi_M \text{ (Schottky – Mott)} \quad (1)$$

where $\Phi_{B,n}$ and $\Phi_{B,p}$ are the n-type and p-type SB height (SBH), and χ_S and I_S are the electron affinity and ionization energy of the semiconductor, respectively.⁵⁹ The SBH should be as low as possible to reduce the contact resistance of the metal–semiconductor junction (MSJ), and ultimately be zero or negative to achieve SB-free contact. Because most electrode metals do not meet the above criteria, investigations of electrode materials with tunable work functions have recently been emphasized for 2D TMD semiconductor devices. The work function of MXenes varies over a wide range with the surface functional groups, composition, and thickness. Based on first-principles calculations, Liu *et al.* reported

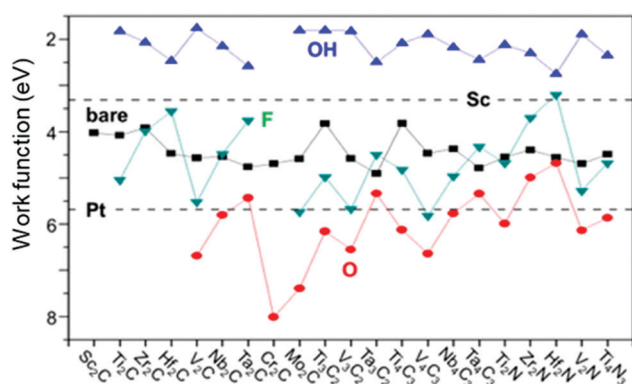


Fig. 4 Work function plots of MXenes with OH-, F- and O- terminations. Reproduced with permission.⁶⁰ Copyright 2016, American Chemical Society.

that the work function of MXenes with OH- and O- terminations on their surface is smaller than that of Sc (3.5 eV) and larger than that of Pt (5.6 eV), respectively, (Fig. 4).⁶⁰ Mixing of O and OH or adding F terminations brings the work function to a moderate level, allowing the use of the material as a work function regulator.

Although the work function of electrode metals seems to be a suitable descriptor of the SBH in MSJ, studies have revealed that the measured SBH is not directly proportional to the metal work function, which deviates from the Schottky–Mott rule.⁶¹ This discrepancy is attributed to Fermi level pinning (FLP), driven by various gap states, including surface states, metal-induced gap states (MIGS), defect-related states, and disorder-induced gap states (DIGS).⁶² Although these states are classified according to their different structural origins, they are fundamentally caused by chemical interactions on the contact. Considering an additional interface dipole ($e\Delta_{\text{dip}}$), which is attributed to charge relaxation at the MSJ, the SBH is modified from the Schottky–Mott model to:

$$\Phi_{B,n} = \phi_M - \chi_S + e\Delta_{\text{dip}}, \quad \Phi_{B,p} = I_S - \phi_M - e\Delta_{\text{dip}} \quad (2)$$

$$e\Delta_{\text{dip}} = \int_{z_1}^{z_2} \int \int z \Delta\rho(x, y, z) dx dy / S \quad (3)$$

where z , $\Delta\rho$, and S are the coordinates normal to the surface, change in the charge density, and surface area, respectively.⁶⁰ The schematic MSJ band diagram, which is modified with various gap states and the interface dipole, is shown in Fig. 5a. Unfortunately, the interface dipole cannot be clearly determined due to the ambiguity of the contributors and bulk states.^{62,63} The linearly fitted slope of the Φ_B -versus- ϕ_M plot is deduced as a measure of the FLP strength, so-called interface behavior parameter, or S_ϕ parameter of the semiconductor (S_ϕ).^{62,64}

$$S_\phi \equiv \left| \frac{\partial\Phi_B}{\partial\phi_M} \right| = \left| 1 + \frac{e\partial\Delta_{\text{dip}}}{\partial\phi_M} \right| \quad (4)$$

$S_\phi = 1$ indicates no pinning. From the experiments, S_ϕ was determined to be 0.1 for the MoS₂-3D metal electrode (Sc, Ti, Ni, and Pt) junction, approximately 0.25 for GaSe, and 0.05 for n-Ge (Fig. 5b).⁶⁵ These small S_ϕ values indicate a weak dependence of SBH on the work function; therefore, in a strong pinning situation, it becomes challenging to achieve SB-free MSJ even if the work function has been largely adjusted.

To avoid lattice mismatch-induced gap states (or DIGS) and MIGS, it is necessary to form TMD and MXene 2D contacts by secondary bonding. The atomically flat and defect-free MSJ, which is difficult to achieve in 3D materials, can be easily achieved with 2D metals and 2D semiconductors *via* their chemically saturated surfaces, consequently suppressing defect-related states. More than 70 MXenes are theoretically expected to afford optimized coupling between MXenes and TMDs. Some recent studies have demonstrated the feasibility of constructing SB-free contacts with black phosphorus, MoS₂, and GaN.^{11b–d} Liu *et al.* investigated the electronic state of T-MoS₂-H-MoS₂ as an example of a 2D-metal–2D-semiconductor *via* DFT calculations and found that the MSJ states originate from the metal rather than the semiconductor, leading to negligible

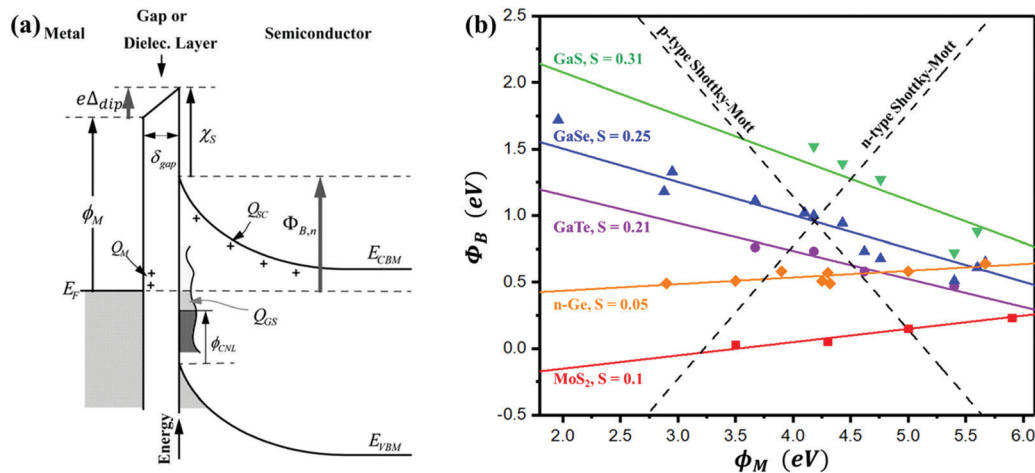


Fig. 5 (a) The fixed separation model for SBH formation. Electronic states, with a charge neutrality level (CNL) and density of states, were assumed to reside on the semiconductor surface, which is held at a fixed distance from the metal. Reproduced with permission.⁶² Copyright 2014 AIP Publishing LLC. (b) SBH versus the contact 3D metal work functions for p-type GaS, GaSe, and GaTe, and n-type n-Ge, and MoS₂.⁶⁵ The solid and dotted lines represent a linear fit to the experimental points and the ideal Schottky–Mott limits with $S = 1$, respectively.

MIGS in the junction (Fig. 6a).^{64b} This is in contrast to the significant MIGS determined in the case of a 3D-metal–2D-semiconductor. The bond distance of T-MoS₂–H-MoS₂ was calculated to be within 3–4 Å, indicating typical vdW interactions, where the vdW interactions were not strong enough to induce MIGS. The suppression of MIGS in the semiconductor can therefore lead to a weak FLP, which was supported by the calculated $S_\phi \cong 1$ for H-MoS₂–2D metals (Fig. 6b).

You *et al.* verified the HER activity of MoS₂ with seven representative O-terminated MXenes (V₂CO₂, Cr₂CO₂, Mo₂CO₂, Ti₃C₂O₂, V₄C₃O₂, Cr₂NO₂, and V₂NO₂), which were used in p-type SB-free contacts with near-zero SBH from –0.185 to +0.245 eV.^{11a} The report suggests that the metallic properties of 2H-MoS₂, induced by the SB-free contact at the interface of MoS₂/MXenes, enhance the hydrogen adsorption ability on the basal plane of 2H-MoS₂, based on an analysis of the hydrogen adsorption energy (ΔE_H) of the heterostructure of MoS₂ with O-terminated MXenes. In more detail, when MXenes with near-zero SBH were contacted with semiconducting 2H-MoS₂, the Fermi level of the MXenes was located at or below the valence band maximum of 2H-MoS₂, which could result in metallic properties of 2H-MoS₂. Therefore, these SB-free p-type 2H-MoS₂/MXenes exhibited enhanced charge transfer kinetics for the HER. As shown in Fig. 7a, the ΔE_H of the 2H-MoS₂/MXenes was considerably lower than that of pristine 2H-MoS₂, reaching values comparable to that of 1T-MoS₂. This could result in dramatically improved H adsorption on the basal plane of 2H-MoS₂ in 2H-MoS₂/MXene hybrids. Furthermore, the adsorption of H on the S vacant sites seemed to be strengthened; ΔE_H for a single S vacancy on the basal plane of 2H-MoS₂/Cr₂CO₂ was –3.08 eV, while that of the pristine MoS₂ was –2.06 eV.

Another important characteristic of the TMD/MXene hybrids relates to the ion diffusion rate and capacity for energy storage applications. The flexibility of the vdW interaction of 2D TMD/MXenes allows the reversible intercalation of guest ions without

significant destruction of the layers. Tang *et al.* recently predicted that proper combinations of MoS₂ and VS₂ with Mo-, Nb-, Ti-, and V-based-MXenes could be effective for application in Na-ion batteries, based on DFT calculations.⁶⁶ First, the study revealed that the interaction between TMDs and bare MXenes was stronger compared to that with O-terminated MXenes, suggesting more potent cohesive energies for the former. All these cohesive energies were negative, which suggests that the construction of stacked TMDs with MXenes is an exothermic reaction. Second, O-terminated MXenes showed a better capacity for intercalating five layers of Na⁺ ions (Fig. 7b) without severe structural distortion due to their large interlayer space (2.59–2.81 Å), compared to those of bare MXenes and TMDs (1.62–2.40 Å). Furthermore, the minimal barriers for layer-to-layer Na⁺ diffusion (0.091–0.371 eV for MoS₂ and 0.097–0.221 eV for VS₂) were sufficient to facilitate fast charge/discharge processes. Considering the optimal adsorption sites of the TMD/MXene structure for Na⁺ ions, five layers of Na⁺ ions could be formed around the TMD/MXenes. The MoS₂/O-terminated MXenes behaved differently from VS₂/O-terminated MXenes; some of the Na⁺ ions escaped from the S-terminated surfaces of MoS₂, whereas no such phenomenon was observed for the latter. On the basis of the above results and by visualizing the electron localization functions (ELFs) along the (110) plane of VS₂ with O-terminated MXenes, they concluded that VS₂ with an O-terminated Ti₂CO₂ structure could accommodate five layers of Na⁺ ions without severe structural distortion upon intercalation of the Na⁺ ions, with rapid charge/discharge processes.

4. Synthesis of TMD decorated MXenes

In recent years, several MXene-TMD composite structures have been reported for various electrochemical applications. The

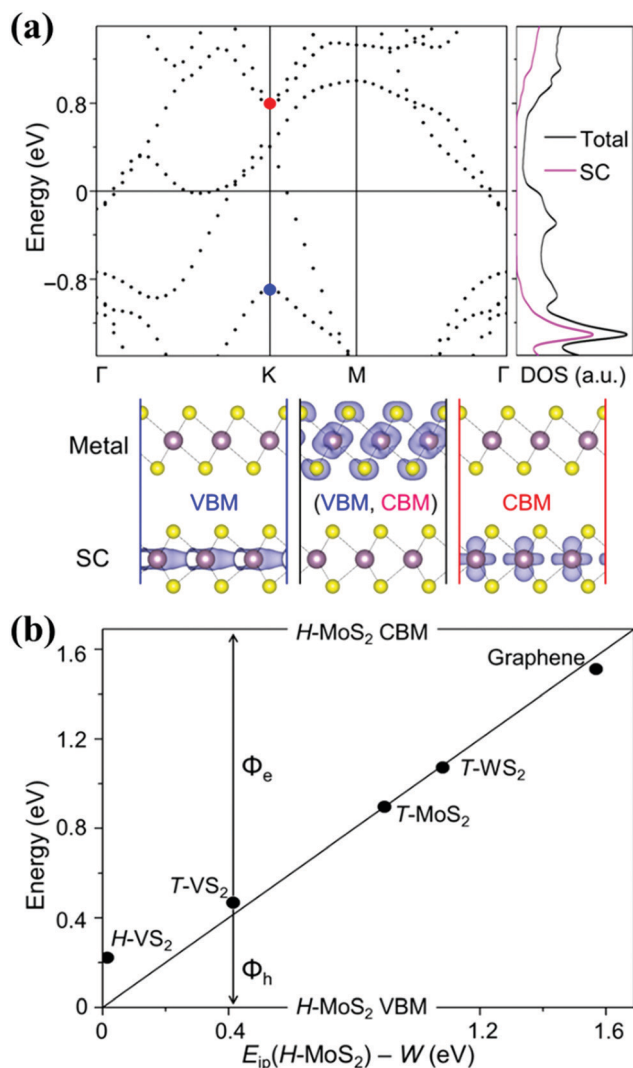


Fig. 6 (a) Electronic band structure and density of states (DOS) of a typical vdW MSJ of metallic T-MoS₂ and semiconductor (SC) H-MoS₂. FL is set to zero. The VBM and CBM of the SC are marked by blue and red dots, respectively. Iso-surfaces show the spatial distributions of the states. (b) SBH versus the contact 2D metal work functions. The diagonal line shows the ideal Schottky–Mott limit. Reproduced with permission.^{64b} Copyright 2016, American Association for the Advancement of Science.

combination of MXene–TMDs forms an open structure in which the stacking issue affecting the individual materials can be resolved, thus maintaining the interlayer space and resulting in fast ion transfer between the sheets, which makes these composites promising and desirable electrode materials. The recent development of various TMD/MXene composite nanostructures is presented in the following subsections (Fig. 8).

4.1. MoS₂–MXene

Among the transition metal dichalcogenides, MoS₂ (bulk and delaminated forms) has been established as a versatile and prominent material for dry lubrication, catalysis, biological, electrochemical, and electronics applications.⁶⁷ Thin 2D MoS₂ affords great electrochemical performance because of its catalytically

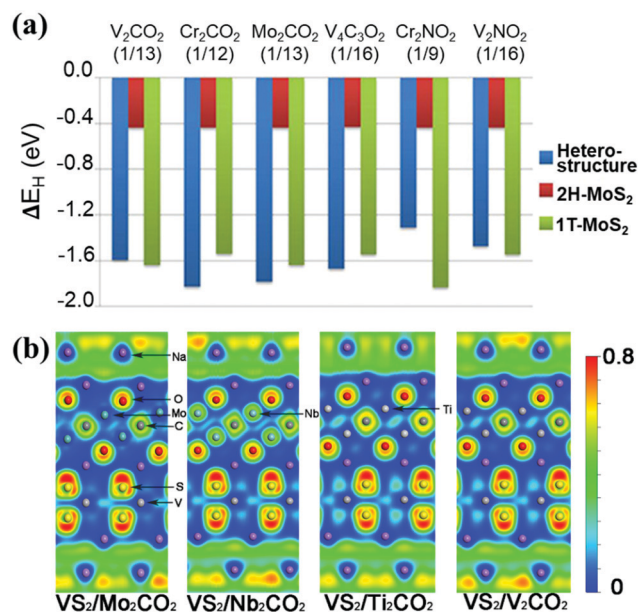


Fig. 7 (a) The plot of hydrogen adsorption energies (ΔE_{H}) of 2H-MoS₂, 1T-MoS₂, and 2H-MoS₂/MXene heterostructures. Reproduced with permission.^{11a} Copyright 2019, American Chemical Society. (b) Electron localization functions for the cross section of the (110) plane of VS₂/Mo₂CO₂, VS₂/Nb₂CO₂, VS₂/Ti₂CO₂, and VS₂/V₂CO₂, respectively, with five layers of Na⁺ ions. Reproduced with permission.⁶⁶ Copyright 2019, American Chemical Society.

active edges, layered dynamic morphology, hydrophilicity, and tunable bandwidth.^{56a,68} Thus, MoS₂ has gained immense interest for electrochemical applications, and its performance is comparable to that of graphene and carbon nanotube electrodes.^{56d,69} However, the significant constraints of MoS₂ include its low intrinsic conductivity, inadequate active sites, oxidation of the edges, limited voltage window, structural disintegration, and poor cycling stability.^{68,70} To address these issues, MoS₂-based composites such as MoS₂-graphene/CNT/Fe₃O₄ hybrid structures have been synthesized, but moderate conductivity and volume expansion still remain major challenges.⁷¹ Two-dimensional MXenes have been proven to be efficient electrode materials owing to their superior metallic conductivity and hydrophilicity combined with cyclability. Therefore, MXene-based MoS₂ hybrid composites have been extensively explored to overcome the above limitations.^{71b} Ti₃C₂ is typically used as a representative MXene material for the synthesis of TMD/MXene-based nanocomposites. A simple sintering method was first introduced by Shen *et al.*, where MoS₂@Ti₃C₂ nanocomposite powder was obtained *via* a solid-phase sintering method using Ti₃C₂ as a starting material.⁷² The hydrothermal method was also applied by Li *et al.* to form a TMD/MXene hybrid, where *in situ* uniform growth of MoS₂ nanolayers was achieved on the surface of Ti₃C₂.^{57b} However, the synthesis of vertically aligned MoS₂ on a Ti₃C₂ support by a hydrothermal process, in the absence of carbon nano-plating, would readily oxidize Ti₃C₂ to TiO₂ and lead to structural degradation.⁷³ Consequently, Attanayake *et al.* reported that the exposure of a colloidal solution of exfoliated Ti₃C₂ and (NH₄)₂MoS₄ to microwaves at a specific temperature generated sufficient heat for the nucleation and perpendicular growth of MoS₂ on the Ti₃C₂ surface. The resulting MoS₂

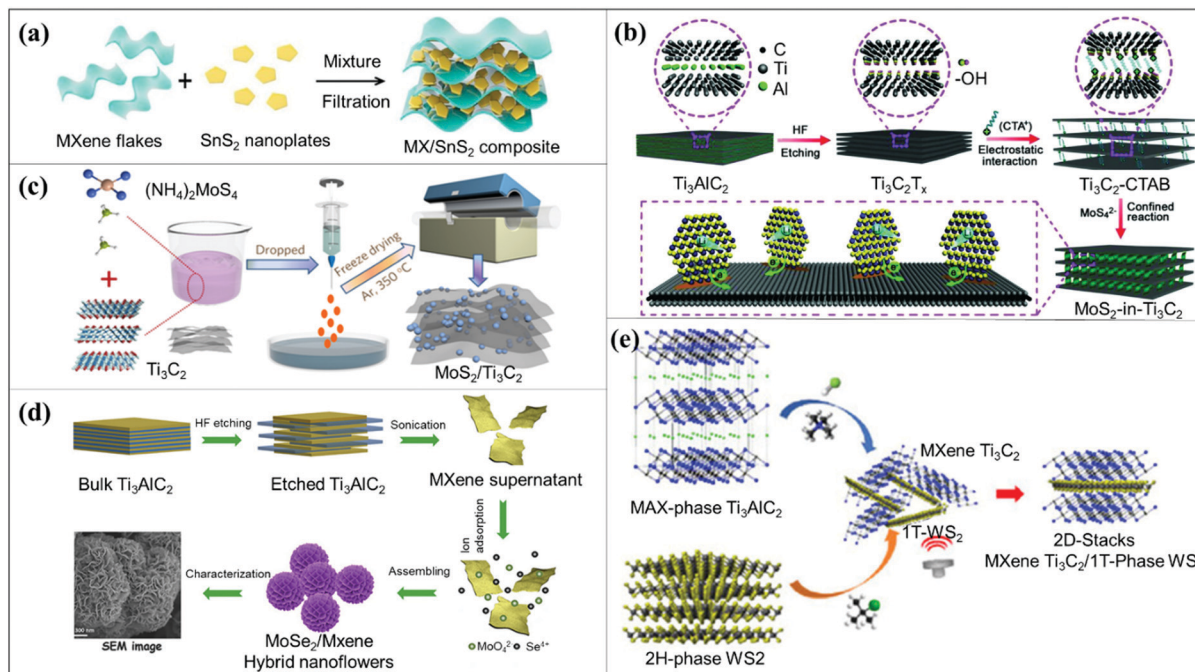


Fig. 8 Various approaches for the synthesis of TMD-MXene hybrid structures. (a) Synthesis of a SnS_2 -MXene composite by sonication and vacuum-assisted filtration through a polypropylene membrane. Reproduced with permission.⁶ Copyright 2018, Elsevier. (b) Synthesis of the MoS_2 -in- Ti_3C_2 (MoS_2 -out- Ti_3C_2) hybrids by electrostatic attraction in the presence (absence) of cetyltrimethyl ammonium bromide. Reproduced with permission.⁷⁵ Copyright 2018, Wiley. (c) Synthesis of $\text{MoS}_2/\text{Ti}_3\text{C}_2$ hybrid material prepared via freeze-drying followed by thermal decomposition. Reproduced with permission.^{71b} Copyright 2020, Wiley. (d) Step-by-step synthesis of $\text{MoSe}_2/\text{MXene}$ hybrid nanoflowers by a simple hydrothermal method; inset picture shows the SEM image of $\text{MoSe}_2/\text{MXene}$ hybrid nanoflowers. Reproduced with permission.⁸² Copyright 2020, Elsevier. (e) Schematic illustration of introduction of 1T- WS_2 between the delaminated matrices of Ti_3C_2 through a simple sonication process to produce a 2D $\text{Ti}_3\text{C}_2/1\text{T-WS}_2$ hybrid structure. Reproduced with permission.¹⁰ Copyright 2019, Wiley.

nanosheets were vertically oriented on the Ti_3C_2 support.⁷⁴ Ma *et al.* and Chen *et al.*, respectively, reported other techniques, including electrostatic interaction and laser engraving-assisted fabrication for the formation of MoS_2 - Ti_3C_2 nanocomposites.^{58e,75} Other MXenes such as Mo_2CT_x ($T = \text{O}, \text{OH},$ or F -terminated groups), V_4C_3 , and $\text{Mo}_2\text{TiC}_2\text{T}_x$ have also been successfully coupled to MoS_2 (Fig. 9a-d).⁷⁶

4.2. WS_2 -MXene

WS_2 is also a naturally occurring layered TMD, and exfoliated WS_2 shows impressive optical and electrochemical/catalytic properties,⁷⁷ making it amenable to diverse applications.⁷⁸ The space present between the sheets of WS_2 allows for intercalation of atoms, forming high-efficiency materials for energy storage applications.⁷⁹ To overcome the intrinsically low electrical conductivity, poor rate capability, low cycling stability, and massive volume expansion of WS_2 , significant efforts have been devoted to fabricating hybrid WS_2 -based nanostructures.⁸⁰ The WS_2 - Ti_3C_2 nanohybrid structure has been easily synthesized due to the abundant nucleation sites provided by Ti_3C_2 for the growth of WS_2 ; Su *et al.* introduced the vapor phase deposition of WS_2 flakes over $\text{Ti}_3\text{C}_2\text{T}_x$.⁸¹ The report suggests that the desired layers of WS_2 flakes can be achieved simply by controlling the growth parameters. Vyskočil *et al.* reported the synthesis of 2D nanohybrids by sonication of delaminated Ti_3C_2 ($\text{Ti}_3\text{C}_2\text{-D}$), prepared using tetrabutylammonium

hydroxide, with different ratios of 1T-phase WS_2 nanolayers.¹⁰ The multilayer stacking arrangement of $\text{Ti}_3\text{C}_2\text{-D}$ and 1T-phase WS_2 was confirmed through transmission electron microscopy (TEM) imaging. The ideal ratio of delaminated Ti_3C_2 to 1T-phase WS_2 was noted to be 90:10 by comparing the capacitance for different ratios of 1T-phase WS_2 .

4.3. Other TMD/MXenes

In addition to MoS_2 and WS_2 , other TMD/MXene-based composites with MoSe_2 , SnS_2 , and WSe_2 have been reported. For example, a MoSe_2 -MXene composite (Fig. 9e and f) was developed by employing a hydrothermal approach followed by annealing.^{57a,82} The MoO_4^{2-} and Se^{4+} ions formed were adsorbed on the surface of ultrasonicated Ti_3C_2 , resulting in the formation of a 3D MoSe_2 - Ti_3C_2 hybrid nanoflower-like structure. On the other hand, Li *et al.* prepared 1T/2H- $\text{MoSe}_2/\text{MXene}$ catalysts via a simple hydrothermal method, where Na_2MoO_4 , Se powder, and NaBH_4 were dispersed in DI water with as-prepared Ti_3C_2 MXene nanosheets.⁸³ This solution was heated in a steel autoclave at 220 °C for 20 h to produce 1T/2H- $\text{MoSe}_2/\text{MXene}$. They revealed the existence of 1T- and 2H- MoSe_2 from the lattice fringes using HRTEM, visualizing the characteristic atomic arrangement of 1T- and 2H- MoSe_2 on the (002) plane, where trigonal and honeycomb atomic arrangements were observed for the 1T and 2H phases, respectively. Raman analysis further showed that the 1T and 2H phases of MoSe_2 coexisted in 1T/2H- $\text{MoSe}_2/\text{MXene}$; the two typical Raman peaks of

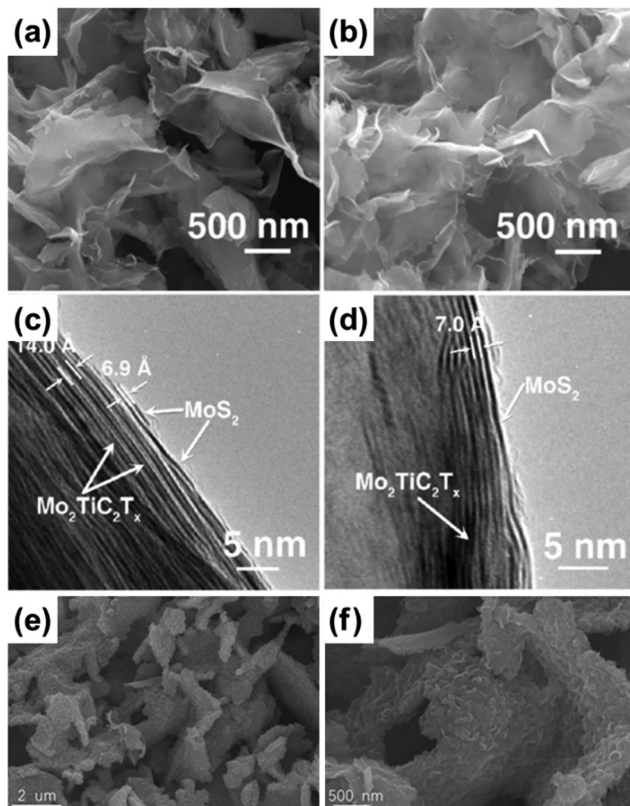


Fig. 9 (a) and (b) SEM images of $\text{MoS}_2/\text{Mo}_2\text{TiC}_2\text{T}_x$ heterostructures at 500 °C and 700 °C, respectively. (c) and (d) Cross-sectional TEM images of $\text{MoS}_2/\text{Mo}_2\text{TiC}_2\text{T}_x$ heterostructures at 500 °C and 700 °C, respectively, indicate 2D layers with MoS_2 on $\text{Mo}_2\text{TiC}_2\text{T}_x$. Reproduced with permission.^{76c} Copyright 2018, Wiley. (e) and (f) FESEM images of $\text{MoSe}_2/\text{Ti}_3\text{C}_2\text{T}_x$ heterostructures at various magnification. Reproduced with permission.^{57a} Copyright 2020, Elsevier.

2H- $\text{MoSe}_2/\text{MXene}$ were observed at 241 (A_{1g}) and 285 cm^{-1} (E_{2g}^1), while the profile of 1T/2H- $\text{MoSe}_2/\text{MXene}$ exhibited not only negatively shifted Raman peaks (5–6 cm^{-1}) for the A_{1g} and E_{2g}^1 states, but also two additional peaks at 195 and 350 cm^{-1} , which were not observed in the Raman spectra of 2H- $\text{MoSe}_2/\text{MXene}$ and MXene. However, the exact ratio between the 1T and 2H phases was not reported.

The synthesis of $\text{SnS}_2\text{-MXene}$ composites was reported by Wu *et al.*, where the composite was synthesized by mixing a colloidal solution of $\text{Ti}_3\text{C}_2\text{T}_x$ with SnS_2 solution at different mass ratios.⁶ The heterostructure of $\text{SnS}_2\text{-Ti}_3\text{C}_2\text{T}_x$ was obtained after vacuum-assisted filtration of the aqueous mixture through a polypropylene membrane. Furthermore, Xu *et al.* (first report on TMD/MXene composites) reported the stacking of mechanically exfoliated $\text{Ti}_2\text{C}(\text{OH})_x\text{F}_y$ flakes on the targeted WSe_2 flakes by a mechanical transfer method to fabricate $\text{WSe}_2\text{-Ti}_2\text{C}(\text{OH})_x\text{F}_y$ heterostructures.⁸⁴

5. Applications towards energy storage and conversion devices

As mentioned earlier, MXenes have high electrical conductivity, and their work function can be modulated by adjusting the

layer thickness or surface termination. The ability to create a vdW heterointerface with TMDs, avoiding FLP, opens a door for applying hybrids of TMDs and MXenes in various fields such as energy conversion, energy storage, photo- and electrocatalysis, and optics.

5.1 Batteries and supercapacitors

Rechargeable batteries are considered a primary tool for energy storage. Thus, various nanomaterials have been explored and developed for fabricating high-performance energy storage materials.⁸⁵ Lithium-ion batteries are of great interest because of their compact, efficient storage mechanism and robust nature, which allow the shuttling of Li^+ ions between the anode (mostly graphite) and cathode (mostly lithium metal oxide).⁸⁶ Over the past decade, graphene-like layered 2D materials have been vastly investigated as electrode materials because of their large surface area, which can provide high capacity, combined with structural permanence.⁸⁷ As electrode materials in Li-ion batteries, graphene and transition metal oxide materials demonstrated superior and comparable capacity (744 and 700 mA h g^{-1} , respectively), with good cyclic stability.⁸⁸ Layered 2D TMDs display low volume change and possess numerous active sites due to their large surface area, making them different from the bulk counterparts; thus, these materials have attracted tremendous interest as electrode materials.⁵²

Several studies have investigated 2D MoS_2 as an anode material for Li-ion batteries. The results revealed that exfoliated MoS_2 affords increased specific capacity (approximately 1131 mA h g^{-1}) and higher coulombic efficiency than the pristine MoS_2 electrode because the slack exfoliated MoS_2 layers can accommodate the volume variation.⁸⁹ Owing to the lack of structural integrity of the anode during the lithiation process and capacity reduction after several cycles, the construction of MoS_2 -based composite electrodes has been highlighted. $\text{MoS}_2@\text{TiO}_2$ hybrid nanostructures prepared by Xu and co-workers afforded substantially improved specific capacity and rate capability.⁹⁰ Chang *et al.* effectively fabricated $\text{MoS}_2/\text{graphene}$ nanosheet layered composites, which exhibited exceptionally high specific capacity and current density (1300 mA h g^{-1} at 100 mA g^{-1} and 1040 mA h g^{-1} at 1000 mA g^{-1}).^{56c} Similarly, as electrode materials, a composite of MoS_2 with SnO_2 and a CNT-supported MoS_2 nanohybrid afforded improved structural integrity with a long cycle life and high rate capability in Li-ion batteries.⁹¹ In MoS_2 -carbon-based electrodes, the presence of carbon sites led to numerous side reactions, which reduced the overall efficiency.^{71b}

2D MXene (Ti_3C_2)-based electrodes exhibit an attractive reversible volumetric capacitance (1375 mA h cm^{-3}), which is twice that of the graphite electrode (550 mA h cm^{-3}), because of the excellent electrochemical properties of the former.⁹² By exploiting the properties of layered MXenes, Hu *et al.* and Du *et al.* reported the synthesis of a $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ hybrid composite as an anode material for Li-ion batteries.^{71b,93} The resulting $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ composite delivered a stable reversible capacitance (614.4 mA h g^{-1} at 100 mA g^{-1}) with low electrochemical impedance and better rate performance (Fig. 10a and b). This performance was mainly attributed to the unique structure and

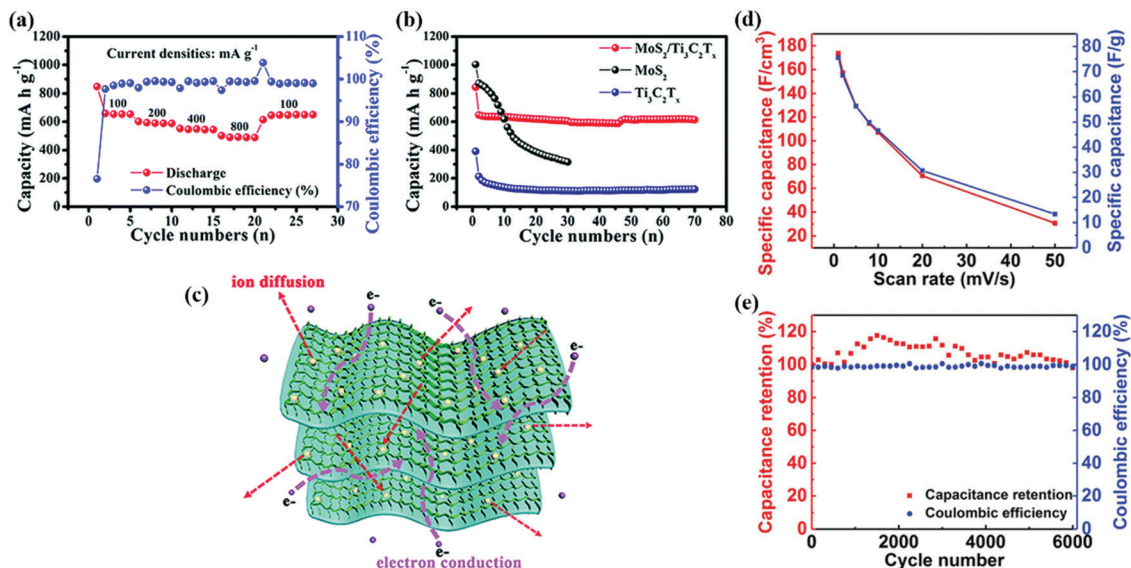


Fig. 10 (a) Rate performance of the $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ composite for different discharge capacities with coulombic efficiency almost 100%. (b) Cycling stability of the $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ composite compared to MoS_2 and $\text{Ti}_3\text{C}_2\text{T}_x$. (c) Schematic representation of MoS_2 layers uniformly distributed over $\text{Ti}_3\text{C}_2\text{T}_x$, along with the ion diffusion and electron conduction paths. Reproduced with permission.⁹³ Copyright 2019, The Royal Society of Chemistry. (d) Specific capacitance of a micro supercapacitor (MXene- MoS_2) at different scan rates. (e) Capacitive reterivity and coulombic efficiency of a micro supercapacitor. Reproduced with permission.^{58e} Copyright 2019, Wiley.

synergistic effect, which hindered the agglomeration and volume expansion of the MoS_2 nanosheets due to the large conductive surface of the $\text{Ti}_3\text{C}_2\text{T}_x$ substrate (Fig. 10c), which promoted rapid electron/ Li^+ transfer kinetics. Similarly, Wu *et al.* assembled $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{MXene}@C$ nanohybrids as anodes and evaluated their utility in lithium batteries using CR2016 coin cells, which had an ideal mass loading of electrodes of approximately $0.8\text{--}1.0\text{ mg cm}^{-2}$. The test demonstrated high capacity and prolonged cycle life (3000 cycles) at a high current density.⁷³ This significant improvement was due to the reduced number of pathways for mass and charge diffusion from the MoS_2 nanostructures, along with the carbon nanoplating, which improved the electronic coupling between the MoS_2 nanostructures with Ti_3C_2 and also provided structural stability.

On the other hand, V_4C_3 exhibited better structural durability and specific capacity as an anode material than Ti_3C_2 .^{76a} Considering this, Bai and co-workers produced a $\text{V}_4\text{C}_3/\text{MoS}_2/\text{C}$ nanohybrid for a high-rate Li-ion battery, which displayed a high specific capacitance at high current rates (622.6 and 500 mA h g^{-1} at 1 and 10 A g^{-1} , respectively), and enhanced cycling efficiency in the potential range of $0.01\text{--}3.0\text{ V}$ (*vs.* Li/Li^+), with an optimal mass loading of $1\text{--}2\text{ mg cm}^{-2}$. The improved electrochemical performance resulted from the increased electrical conductivity and structural stability due to V_4C_3 and the thin carbon coating, while the MoS_2 nanosheets led to higher specific capacitance and enhanced charge mobility. Because sodium-ion batteries are regarded as a cheaper alternative to Li-ion batteries, extensive studies have been dedicated to identifying an optimum anode material for these batteries.⁹⁴ With respect to this, Wu *et al.* reported $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ composites synthesized by the hydrothermal method as an anode material for Na-ion batteries.^{11g} The evaluation

of the electrochemical properties of the $\text{MoS}_2/\text{Ti}_3\text{C}_2\text{T}_x$ composite using a CR2032 coin-type cell with Na-metal as the counter-electrode, within the voltage window of $0.01\text{--}3.0\text{ V}$ (*vs.* Na/Na^+), demonstrated the excellent reversible capacity (250.9 mA h g^{-1} at 100 mA g^{-1}), high cycling stability, and rate capability, attributed to the nested architecture of the composite. While the MoS_2 nanosheets increased the capacity of the composite, the presence of $\text{Ti}_3\text{C}_2\text{T}_x$ favored the open structure, and the decreased concentration of fluorine on the surface afforded improved electrochemical performance of the composite. The weak van der Waals forces of MoS_2 and the large interlayer spaces of MXene, capable of accommodating various cations (such as Na^+ , K^+ , NH_4^+ , Mg^{2+} , and Al^{3+}), have attracted great interest for the use of these materials in non-lithium batteries.^{56a,95} Inspired by this, the possibility of using $\text{MoS}_2\text{--MXene}$ composite electrodes in magnesium, potassium, and lithium-sulfur batteries has been explored.^{57b,96} Electrochemical measurements displayed superior reversible capacity, remarkable rate performance, and cycling durability. However, research on $\text{MoS}_2\text{--MXene}$ composites for non-lithium batteries is still at an early stage, calling for further study.

Seo *et al.* and Sun *et al.* reported SnS_2 as an electrode material for Li-ion and Na-ion batteries, respectively, and achieved exceptional specific capacity, rate performance, and cyclability.⁹⁷ To overcome the inherent constraints of SnS_2 , such as tremendous volume change and large capacity fading in Na-ion batteries, Wu and co-workers subjected the $\text{Ti}_3\text{C}_2\text{T}_x/\text{SnS}_2$ heterostructure (mass ratio MXene/ $\text{SnS}_2 = 1:5$) to charge/discharge tests within the potential range of $0.01\text{--}2.5\text{ V}$ (*vs.* Na/Na^+) using LAND 2001A. They demonstrated that the specific capacity was maintained, even at high temperatures, when used as an anode material.⁶ Li *et al.* prepared a $\text{Ti}_3\text{C}_2\text{T}_x$ -decorated

SnS₂/Sn₃S₄ hybrid *via* a solvothermal process and examined the resultant composite as an anode for Li-ion batteries, within the voltage range of 0.005–3.0 V, at room temperature.^{11e} Interestingly, the composite displayed steady cycling performance, with notable rate capability, attributed to expeditious electron transfer with little volume variation. Furthermore, the increased surface interaction between the electrode and electrolyte due to the large specific area of SnS₂/Sn₃S₄ led to partial pseudocapacitance at high current densities, thereby increasing the Li⁺ ion diffusion. Li and co-workers recently studied a MoSe₂/MXene heterojunction for Na-ion batteries, with an average electrode loading mass of approximately 1.1 mg cm⁻². The battery could maintain reversible capacity at a high current density and exhibited promising electrochemical qualities.^{57a} The mechanism of rapid Na⁺ ion shuttling and the better electronic structure of MoSe₂/MXene were confirmed theoretically (density-functional theory calculations) and experimentally (galvanostatic intermittent titration and electrochemical impedance spectroscopy).

Supercapacitors belong to a class of electrochemical energy storage devices and can deliver higher power densities quickly with protracted charge/discharge cycles compared to batteries.⁹⁸ Graphene is considered one of the best-suited materials for supercapacitors owing to its high surface area, excellent conductivity, intrinsic stability, and high volumetric capacitance (376 F cm⁻³).⁹⁹ However, during charging and discharging, these materials undesirably undergo layer restacking, which decreases the charge storage due to the restricted availability of the surface area. The use of hydrous ruthenium oxide in pseudocapacitors afforded impressive supercapacitance (~900 F g⁻¹) and cycling efficiency. However, when the water content was reduced, the capacitance also decreased (to 29 F g⁻¹).¹⁰⁰ On the other hand, MXenes combine large surface areas with superior hydrophilicity and conductivity and provide significantly high capacitance, exceeding that of the best-known carbon supercapacitor.^{14b} Ghidui *et al.* first introduced a new, safe, and easy protocol for the synthesis of additive-free clay-like MXenes and provided a faster approach for obtaining delaminated flakes.¹⁵ When these clay-like MXenes were rolled into thin sheets for supercapacitor electrodes, they displayed remarkable volumetric capacitance of up to 900 F cm⁻³ and better rate-handling ability. However, the aggregation of the layers inhibited the complete utilization of MXene, which hindered ion transport and strongly reduced the capacity. Acerce and co-workers showed that metallic 1T-phase MoS₂ nanosheets can be chemically exfoliated to facilitate the intercalation of various cations (H⁺, Li⁺, Na⁺, and K⁺), leading to high capacitance (~400–700 F cm⁻³) with excellent cycling stability (about 5000 cycles) in both aqueous and organic electrolytes.^{56a} The ability of the exfoliated layers to expand, along with the high hydrophilicity and electrical conductivity (nearly 10⁷ times higher than those of the semiconducting 2H phase) of the 1T MoS₂ phase, resulted in excellent electrochemical properties. By introducing MoS₂ between the MXene sheets, the intrinsic drawbacks of both materials can be eliminated, thereby enhancing the electrochemical performance. Only recently, the 1T-phase WS₂/Ti₃C₂ nanohybrid was studied, where a high capacitance (157 F g⁻¹) was observed for 90% Ti₃C₂/10% 1T-phase

WS₂, and no improvement was observed upon further addition of 1T-phase WS₂.¹⁰ The study discussed the increase in the capacitance for each step of exfoliation of Ti₃C₂, where a substantial increase (nearly 59%) was observed upon inserting WS₂ due to the larger exposed surface area. The enhanced capacitance of the nanohybrid was comparable to that of other hybrid materials. Designing an efficient microsupercapacitor is crucial for portable and wearable electronics. Recently, Chen *et al.* synthesized a Ti₃C₂T_x-MoS₂ film by direct laser etching and evaluated the results for a microsupercapacitor.^{58e} The composite afforded a significantly high specific capacitance (173.6 F cm⁻³, which is 60% more than that of pristine MXene), good coulombic efficiency (around 98%), and longer cycling rates (approximately 6000) (Fig. 10d and e). The study also demonstrated the great flexibility of the hybrid electrode, wherein 89% of the capacitance was retained when the electrode was bent at an angle of 150°.

Although the majority of the research has focused on developing MXene-TMD heterostructures for lithium batteries, MXene-TMD heterostructures have also displayed promising results as functional materials for non-lithium batteries. Among the large families of MXene and TMD materials, Ti₃C₂T_x and MoS₂ have been the forerunners. However, the successful reversible transformation of MoS₂ from Li₂S during discharging and charge storage needs to be studied in detail. Significant focus needs to be placed on research for developing TMD-MXene composites for supercapacitor materials to further advance energy storage devices.

5.2 Electrochemical energy conversion

Among TMDs, molybdenum- and tungsten-based disulfides and diselenides are the most widely utilized electrocatalysts due to their excellent and efficient electrochemical catalytic performance in energy conversion applications, such as the hydrogen evolution reaction (HER), oxygen evolution reaction (OER), and oxygen reduction reaction (ORR).^{9b,101} However, as mentioned in Section 3.1, one of the critical weaknesses of TMDs is the low conductivity of the 2H phase.⁸³ Therefore, the construction of a hybrid structure with highly conductive MXene is an ingenious solution that has been adopted to overcome the low electrical conductance of the 2H phase in electrochemical applications. According to a report by Attanyake *et al.*, MoS₂ nanosheets vertically grown on Ti₃C₂ nanosheets (MoS₂ ⊥ Ti₃C₂@240) were prepared at reaction temperatures of 200–260 °C.⁷⁴ The edge density of MoS₂ was controlled by the reaction temperature, and the highest density of MoS₂ edges was obtained at 240 °C due to the complete reduction of the (NH₄)₂MoS₄ precursor (Fig. 11a). Evaluation of the electrocatalytic HER performance of the composite showed that the HER activity of the MoS₂ ⊥ Ti₃C₂ catalysts was proportional to the edge density of MoS₂, as shown in Fig. 11b, and the optimal overpotential to drive the current density of 10 mA cm⁻² was 110 mV for MoS₂ ⊥ Ti₃C₂@240, with a Tafel slope of ~40 mV dec⁻¹. Moreover, MXenes are known to be metastable due to their poor oxygen resistance under oxygen-rich conditions (even under ambient conditions).¹⁰² As a result of the undesirable spontaneous oxidation, transformation to metal oxides has been reported for

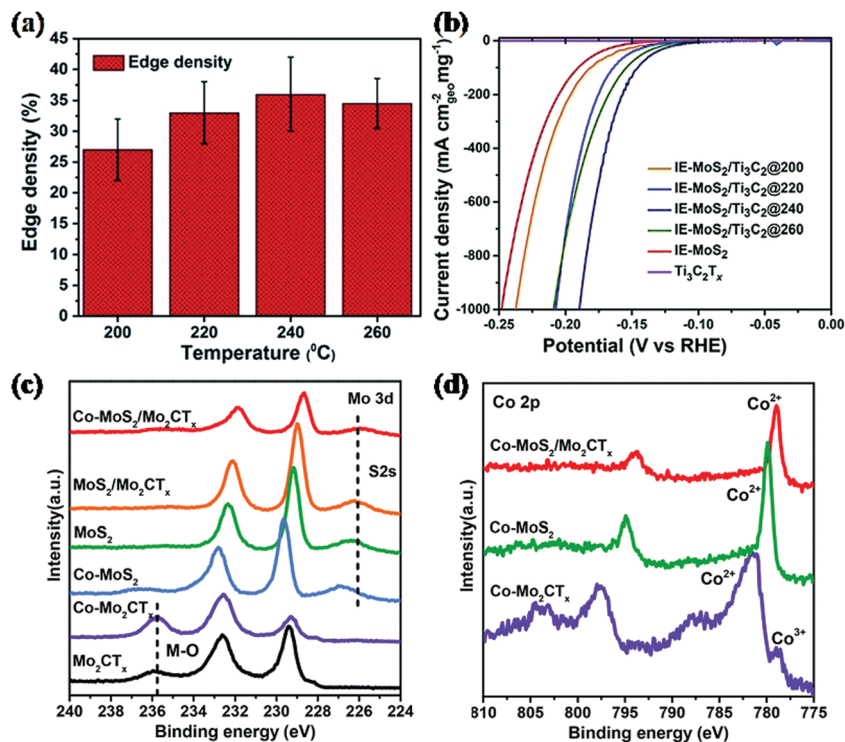


Fig. 11 (a) Edge density plots and (b) HER polarization plots in 0.5 M H₂SO₄ solution of IE-MoS₂/Ti₃C₂ sheets prepared at 200, 220, 240, and 260 °C. Reproduced with permission.⁷⁴ Copyright 2018, The Royal Society of Chemistry. X-ray photoelectron spectroscopy (XPS) spectra of (c) Mo 3d and (d) Co 2p of different materials. Reproduced with permission.^{105b} Copyright 2019, The Royal Society of Chemistry.

several MXenes, leading to a decrease in the catalyst stability and activity.¹⁰³ Wu *et al.* reported carbon nano-plating as an effective strategy for constructing a MoS₂/Ti₃C₂ hybrid with improved HER stability and catalytic activity.⁷³ The surface of Ti₃C₂ MXene was protected by the carbonization of glucose by a facile hydrothermal method and subsequent annealing. The HER performance of MoS₂/Ti₃C₂-MXene@C in 0.5 M H₂SO₄ was compared to that of a hybrid of MoS₂ and oxidized Ti₃C₂ MXene (MoS₂@oxidized MXene) without carbon nano-plating. The overpotential at a current density of 10 mA cm⁻² (η^{10}) for MoS₂/Ti₃C₂-MXene@C was found to be 135 mV, whereas that of MoS₂@oxidized MXene was ~350 mV. The improved catalyst activity was attributed to the prevention of the direct exposure of MXene to the environment, where the charge transfer resistance (R_{ct}) of MoS₂/Ti₃C₂-MXene@C (39 Ω) was significantly lowered due to the carbon nano-plating, whereas the charge transfer resistance of MoS₂@oxidized MXene was 57 Ω . Additionally, MoS₂/Ti₃C₂-MXene@C showed better long-term stability of up to 2000 cycles, as demonstrated by chronoamperometric study at -130 mV for 20 h. Recently, Ren *et al.* reported a Mo-based MXene hybrid HER catalyst with MoS₂ nanoflowers (MoS₂@Mo₂CT_x) instead of Ti-based MXene. In 1.0 M KOH solution, the η^{10} of MoS₂@Mo₂CT_x was 176 mV, whereas the η^{10} of Mo₂CT_x and MoS₂ was 533 and 394 mV, respectively.^{76b} This highly synergistic HER performance of MoS₂@Mo₂CT_x could be achieved by the fast electron transport induced by the intrinsic conductivity of Mo₂CT_x and the numerous exposed active sites for hydrogen adsorption on the MoS₂

nanoflowers. The electrochemical impedance of MoS₂@Mo₂CT_x was only 26 Ω , compared to that of MoS₂ (660 Ω) and Mo₂CT_x (155 Ω). The double-layer capacitance (C_{dl}), which is related to the electrochemically active surface area (ECSA) of Mo₂CT_x (106 mF cm⁻²) was the highest in MoS₂@Mo₂CT_x (the C_{dl} of MoS₂ and Mo₂CT_x was 21.7 and 22.6 mF cm⁻², respectively). In contrast to the above examples, Lim *et al.* oxidized MXenes to prepare nanohybrids of 2H-MoS₂ on Mo₂CT_x MXene for the HER *via in situ* sulfidation of an adventitious oxide layer on Mo₂CT_x.¹⁰⁴ Mo₂CT_x/2H-MoS₂ required an overpotential of only 119 mV to reach a current density of 10 mA cm⁻² in 0.5 M H₂SO₄ solution. They claimed that this exceptionally high HER activity originated from the epitaxially grown lattice interface between Mo₂CT_x and 2H-MoS₂, where the oxidation layers were removed by sulfidation.

Furthermore, the optimized weight ratio of TMD to MXene and doping on the TMDs was suggested as a strategy for improving the electrochemical water splitting performance.¹⁰⁵ Huang *et al.* synthesized a series of weight ratio-controlled hierarchical 2H-MoS₂ nanosheets grown vertically on Ti₃C₂ MXenes (MoS₂/Ti₃C₂ heterostructures).^{105a} The HER activity of the MoS₂/Ti₃C₂ heterostructures was demonstrated in 0.5 M H₂SO₄ electrolytes, and the overpotentials required to reach a current density of 10 mA cm⁻² were optimized for MoS₂/Ti₃C₂-5% (~280 mV), with a Tafel slope of 68 mV dec⁻¹. Although the exact values of the overpotentials of the other materials (MoS₂/Ti₃C₂-1%, -10%, and -20%) were not mentioned, the difference in the activity of the various catalysts could be distinguished from the

polarization plots. The enhanced HER activity of the MoS₂/Ti₃C₂-5% catalyst was associated with the strong interfacial coupling between MoS₂ and Ti₃C₂ at that component ratio, which resulted in enhanced charge transfer. Indeed, among the catalysts, the Tafel slope was the smallest for MoS₂/Ti₃C₂-5%; the Tafel slopes of MoS₃/Ti₃C₂-1%, -10%, and -20% were reported to be 109, 74, and 90 mV dec⁻¹, respectively. In addition, the increased number of active sites of MoS₂/Ti₃C₂-5% could afford an enhanced activity, as suggested by the larger C_{dl} value (61.3 mF cm⁻²) compared to that of the MoS₃/Ti₃C₂-1, -10, and -20% catalysts (41.3, 57.1, and 47.0 mF cm⁻², respectively). According to a recent report by Liang *et al.*, the Co-doped MoS₂ hybrid structure with Mo₂CT_x MXene afforded enhanced alkaline HER performance.^{105b} The study revealed that Co doping could modulate the electronic structure of MoS₂ to reduce the kinetic barrier during the water dissociation step, promoting OH⁻ desorption, as reported in earlier work.¹⁰⁶ The Mo₂CT_x MXene synergistically serves as a superior conductive support to promote charge transfer by strong coupling with Co-doped MoS₂.^{105b} The Mo 3d XPS profile showed a negative shift in the binding energy peak of Co-MoS₂/Mo₂CT_x (-0.5 eV) and MoS₂/Mo₂CT_x (-0.2 eV) compared to that of pristine MoS₂ (the Mo 3d_{5/2} and 3d_{3/2} peaks were observed at 229.2 and 232.3 eV, respectively), indicating strong coupling between MoS₂ and Mo₂CT_x, and consequently efficient electron transfer from Mo₂CT_x to MoS₂ (Fig. 11c). The -1.1 eV shift of the Co 2p peak of Co-MoS₂/Mo₂CT_x relative to that of Co-MoS₂ suggests strong coupling between Co-MoS₂ and Mo₂CT_x (Fig. 11d). The η¹⁰ of Co-MoS₂/Mo₂CT_x for the HER in 1.0 M KOH solution was 112 mV, while those of MoS₂, Mo₂CT_x, Co-MoS₂, Co-Mo₂CT_x, and MoS₂/Mo₂CT_x were 345, 280, 215, 365, and 204 mV, respectively. Furthermore, the smallest Tafel slope of 82 mV dec⁻¹ and R_{ct} of 50 Ω were obtained for Co-MoS₂/Mo₂CT_x, suggesting that Co doping of MoS₂ on Mo₂CT_x MXene effectively enhanced the HER activity of the TMD/MXene hybrid by modulating the electronic structure and further improving the conductivity.

Despite the great achievements in the use of TMDs in electrochemical applications, relatively few examples of hybrid TMDs and MXenes have been reported for the OER, ORR, and CO₂RR. However, some strategies for improving the electrocatalytic OER and ORR performance have recently emerged.^{83,107} Li *et al.* combined multiphasic 1T/2H-MoSe₂ nanosheets with Ti₃C₂ MXene nanosheets to construct active and stable bifunctional electrocatalysts for water splitting in alkaline solution.⁸³ The formation of such composites can be attributed to the intrinsic properties of MoSe₂; the 1T phase is metallic and metastable, while the 2H phase is semiconducting and thermodynamically stable. Thus, the mixed phase comprising 1T- and 2H-MoSe₂ may simultaneously afford enhanced HER activity and stability, and the introduction of MXene with high conductivity may enhance the catalytic activity, providing rapid charge transfer in the catalyst. The bifunctional 1T/2H-MoSe₂/MXene catalyst showed good electrocatalytic performance towards water splitting in 1.0 M KOH solution. The overpotentials of 1T/2H-MoSe₂/MXene to drive the current density of 10 mA cm⁻² were 95 mV (HER) and 340 mV (OER), respectively, while

comparatively larger values were observed for 2H MoSe₂/MXene (123 mV (HER) and 380 mV (OER)). The Tafel slopes of 1T/2H-MoSe₂/MXene for the HER (91 mV dec⁻¹) and OER (90 mV dec⁻¹) were smaller than those of 2H-MoSe₂/MXene (111 mV dec⁻¹). Furthermore, the evaluation of the long-term stability for overall water splitting, determined by chronopotentiometry, demonstrated better stability, where the current density of ~10 mA cm⁻² was maintained at 1.64 V for 50 h. The study reveals that mixing the 1T/2H phases effectively enhanced the electrocatalytic activity and stability for electrochemical water splitting. Pang *et al.* provided an interesting approach for fabricating TMD/MXene hybrids for the OER.^{107b} Instead of constructing the hybrid structure by merging the existing TMD and MXene, the TMD/MXene-like structure was synthesized *via* a bottom-up approach (Fig. 12a). The obtained M₂Q₂C compounds (M, Q, and X correspond to transition metals, chalcogenides, and carbon or nitrogen, respectively) presented good conductivity and enriched active sites. Using this approach, the authors generated Nb₂Se₂C compounds *via* solid-state synthesis. Confirmation of the crystal structure by Rietveld refinement of the XRD pattern revealed that Nb₂Se₂C was iso-structural with Ta₂S₂C and belonged to the hexagonal crystal system (P3m1 space group). In addition, the electronic band structures calculated using density functional theory (DFT) indicated that there was an apparent overlap between the conduction and valence bands, suggesting that Nb₂Se₂C is a semi-metallic material. The electrocatalytic OER performance of Nb₂Se₂C was tested in 1.0 M KOH electrolyte, and a current density of 10 mA cm⁻² was achieved at an overpotential of 321 mV, with a Tafel slope of 238 mV dec⁻¹, whereas NbSe₂ required an overpotential of 415 mV, with a Tafel slope of 329 mV dec⁻¹ (Fig. 12b). EIS analysis demonstrated that Nb₂Se₂C (60.89 Ω) had smaller charge transfer resistance than NbSe₂ (184.3 Ω), RuO₂ (60.89 Ω), and IrO₂ (84.59 Ω). In addition, chronoamperometry indicated that Nb₂Se₂C showed good long-term stability, where the current density of 10 mA cm⁻² was maintained (>98.0%) at 350 mV for 24 h. Recently, Yang *et al.* reported a TMD/MXene hybrid quantum dot (QD) structure with carbon nanotubes (CNTs) as an electrocatalyst for the ORR under alkaline conditions (Fig. 12c).^{107a} The higher surface area of QD MoS₂ with exposed edge atoms relative to that of the nanosheets is believed to provide extra active sites. Hybrid multiwalled CNTs decorated with MoS₂ and Ti₃C₂T_x QDs (MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs), which interact with each other through van der Waals forces, were prepared by simple stoichiometric mixing in solution. The hybrid structure exhibited outstanding ORR activity; the half-wave potential was 0.75 V (*vs.* RHE) with a Tafel slope of ~90 mV dec⁻¹, while that of commercial Pt/C was 0.80 V with a Tafel slope of 89 mV dec⁻¹ (Fig. 12d). However, the mass activity of the MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs (~27 A g⁻¹) at 0.35 V was somewhat smaller than that of Pt/C (~36 A g⁻¹), requiring further optimization of the hybrid structure.

So far, studies on the TMD/MXene hybrid system have mainly focused on their inherent high catalytic activity. The strategy for enhancing electron transfer by the SB-free 2D contact with highly conductive MXene would stimulate new ideas for the next designs of catalysts. Despite the existing promising reports, the

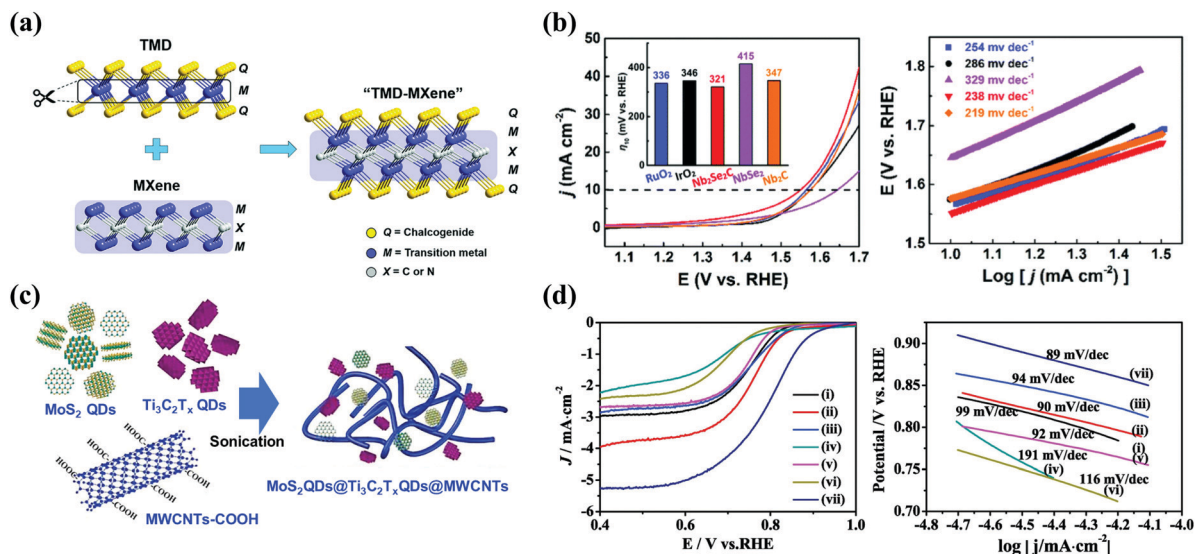


Fig. 12 (a) Schematic illustration of the concept for a "TMD-MXene"-like compound. (b) OER polarization curves in 0.1 M KOH solution (left) with the comparison of the overpotentials at 10 mA cm⁻² (inset) and Tafel plots (right) of RuO₂, IrO₂, Nb₂Se₂C, NbSe₂, and Nb₂C. Reproduced with permission.^{107b} Copyright 2020, The Royal Society of Chemistry. (c) Schematic diagram of the preparation of MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs. (d) ORR polarization curves in O₂-saturated 1.0 M KOH solution (left) and Tafel plots (right) of (i) MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs-1, (ii) MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs-2, (iii) MoS₂QDs@Ti₃C₂T_xQDs@MWCNTs-3, (iv) Ti₃C₂T_x QDs, (v) MWCNTs, (vi) MoS₂ QDs, and (vii) Pt/C at 0.5 V. Reproduced with permission.^{107a} Copyright 2019, Elsevier B.V.

catalytic stability of the TMD/MXene hybrids is still far from being satisfactory due to the poor oxygen resistance of MXene. Therefore, the efforts to enhance the oxidation stability of MXene or to explore less oxidative catalysis should be exerted in the future works.

6. Summary and outlook

The development of 2D materials has received substantial attention because of the outstanding physical and electrical properties of these materials. Atomic flat sheets without defects could be laminated by secondary bonding, providing flexibility and wide inter-sheet space, allowing facile ion intercalation and extraction without destroying the structures. Properties such as the electrical carrier mobility, work function, hydrophilicity, and transparency can be adjusted by controlling the layer thickness or by surface treatment, and importantly, SB-free MSJs with dramatically lower contact resistance can be achieved. In this review, we systematically discussed the recent advances in 2D TMD-decorated MXene hybrid composites for electrochemical electrode-based applications such as batteries, supercapacitors, water splitting, and fuel cells. Among the 2D materials, MXenes and TMDs have advantages such as large specific area, good electrical properties, and an atomically thin layered structure, making them prominent candidates for various applications. In particular, the synergy from the construction of 2D heterojunctions between semiconducting TMDs and metallic MXenes could favorably influence electrochemical applications by modulating the work function or binding strength of the MSJ. Here, we present a comprehensive overview in Table 1, summarizing the

synthesis approaches, material compositions, and applications of TMD-decorated MXenes as electrode materials for energy conversion and storage, which have been presented in recent years. In addition, recent developments have suggested the advantages of TMD-decorated MXene materials in diverse research applications.^{84,108}

Because the electrocatalytic reaction takes place on the surface of the materials, research on MXenes with different termini on the basal plane, such as O, OH, or F, would be critical for such applications.¹⁰⁹ Therefore, careful surface modification of MXenes by controlling the amount and type of terminal elements will play a significant role in enhancing the performance of energy conversion applications using TMD-MXene hybrids. Furthermore, as described earlier, the surface termination of MXenes is affected by the type of etchant used for the extraction of the 'A' site atoms in MAX powders. Thus, MXenes with F-termini are often generated due to the frequent use of F-containing etchants such as HF. MXenes with different functional groups, such as F- and OH-terminated MXenes, may provide remarkable interactions with not only TMDs, but also reactants. Further diversification of the surface treatment is required to optimize or enhance the catalytic performance. For example, the metal-free sulfur nanoparticles could be treated on the surface of MXene by melt diffusion.¹¹⁰ The strong interaction between Ti and S atoms can replace the hydroxyl groups on the MXene. To utilize the electronic interaction or hydrogen bonding formation, grafting charged or O-containing polymers, such as polyvinyl alcohol (PVA), poly(diallyldimethylammonium chloride (PDDA), poly(2-(dimethylamino)ethyl methacrylate (PDMAEMA), and sodium alginate (SA), onto MXene might be another great tool for surface engineering to modulate the

Table 1 Summary of synthesis, applications, and their performance of TMD/MXenes

Parent materials		Synthesis	Initial reversible capacity (mA h g ⁻¹ /A g ⁻¹)	Cycling performance (residual capacity/cycles@A ⁻¹)		Ref.	
TMD	MXene						
Li-ion batteries							
MoS ₂	Ti ₃ C ₂	Hydrothermal	451.3/1	79%/1300@1		7a	
MoS ₂	V ₄ C ₃	Hydrothermal	933.7/1	67%/450@1		76a	
MoS ₂	Ti ₃ C ₂ T _x	<i>In situ</i> sulfidation	554/0.1	92%/100@1		76c	
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	339/0.1	98%/70@0.1		93	
MoS ₂	Ti ₃ C ₂	Solid state sintering	246.1/0.05	100%/200@0.1		72	
MoS ₂	Ti ₃ C ₂	Freeze-drying and thermal treatment	645.4/0.5	130%/1390@5		71b	
MoS ₂	Ti ₃ C ₂ @C	Hydrothermal	1750/0.2	95%/3000@20		73	
SnS ₂ /SnS ₄	Ti ₃ C ₂ T _x	Solvothermal and calcination	462.3/0.1	47%/500@5		11e	
MoS ₂	Ti ₃ C ₂	Electrostatic attraction and (CTAB)-directed growth	914/0.1	100%/1000@0.5		75	
Na-ion batteries							
MoS ₂	Ti ₃ C ₂	Electrostatic attraction and (CTAB)-directed growth	310/1	—		75	
MoSe ₂	Ti ₃ C ₂ T _x	Hydrothermal	559/0.5	91%/400@2		57a	
SnS ₂	Ti ₃ C ₂ T _x	Hydrothermal	377/0.1	85%/200 @ 0.1		6	
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	285.4/0.1	88%/100 @ 0.1		11g	
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	356.2/0.1	93%/70 @ 0.1		93	
Other batteries							
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	K-ion	233.1/0.1	75.9%/100@0.05		57b
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	Mg-ion	165/0.5	65%/50@0.05		96a
1T-2H MoS ₂	Ti ₃ C ₂	Hydrothermal	Li-S	1014.1/0.5 C	79%/300@0.5 C		96b
Supercapacitor							
MoS ₂	Ti ₃ C ₂ T _x	Laser etching		173.6 F cm ⁻³		58e	
1TWS ₂	Ti ₃ C ₂	Sonication		157 F g ⁻¹		10	
TMD	MXene	Synthesis	Overpotential at 10 mA cm ⁻² (mV)	Tafel slope (mV dec ⁻¹)	Loading (mg cm ⁻²)	Electrolyte	Ref.
HER							
MoS ₂	Mo ₂ CT _x	Hydrothermal	176	98	0.71	1 M KOH	76b
MoS ₂	Ti ₃ C ₂	Microwave heating	110	~40	0.071	0.5 M H ₂ SO ₄	74
MoS ₂	Ti ₃ C ₂ @C	Hydrothermal	135	45	0.4	0.5 M H ₂ SO ₄	73
MoS ₂	Ti ₃ C ₂	Hydrothermal	~280	68	—	0.5 M H ₂ SO ₄	105a
Co-MoS ₂	Mo ₂ CT _x	Annealing	112	82	0.354	1 M KOH	105b
MoSe ₂	Ti ₃ C ₂	Hydrothermal	180	91	0.28	0.5 M H ₂ SO ₄	82
1T/2H MoSe ₂	Ti ₃ C ₂	Hydrothermal	95	90	2~3	1 M KOH	83
OER							
NbSe ₂	Nb ₂ C	Solid state sintering	321	238	~2.65	1 M KOH	107b
1T/2H MoSe ₂	Ti ₃ C ₂	Hydrothermal	340	91	2~3	1 M KOH	83
TMD	MXene	Synthesis	E _{1/2}	Mass activity	Tafel slope (mV dec ⁻¹)	Electrolyte	Ref.
ORR							
MoS ₂	Ti ₃ C ₂ T _x	Hydrothermal	0.75 V	~27 A g ⁻¹	90	1 M KOH	107a

electrical and mechanical properties.^{13,22c,111} However, surface engineering should address the persistent concern about restacking between the 2D materials due to van der Waals or hydrogen bonding interactions. Despite the efforts of many research groups, the facile oxidation of MXenes has not been fully resolved, leading to a deleterious impact on the catalytic performance of TMD/MXene composites. Thus, oxidative or oxygen-involved catalytic applications such as the OER or ORR would be negatively impacted by degradation problems. Catalyst architectures beyond the 2D-2D heterostructure should be considered, as specified in this review. The development of QD MoS₂ and MXenes on CNTs proved the possibility

of other heterojunction types for electrochemical applications (ORR and MOR), although these species were deposited on the CNTs.^{107a} Thus, improving and developing the interfacial and spatial design of TMD/MXene composites is inevitable for achieving advanced electrochemical applications.

Research on energy storage and conversion applications with TMD/MXene hybrids is in the infancy stage, and much has to be done to identify the ideal structural features, and synthesis routes. Thus far, complementary computational studies have been performed with various hypothetical TMD/MXene hybrid models, and many TMD/MXene hybrid candidates have been proposed as electrode materials for energy-related applications.

However, theoretical considerations are generally based on oversimplified and idealized models because of the limited computing resources, leading to an overly optimistic vision for these materials.¹¹² Therefore, it is necessary to develop methodologies for synthesizing structurally well-defined TMD/MXene hybrids, which are forecasted to afford excellent performance, and to test their performance. In doing so, the surface chemistry of TMD/MXene hybrids and their electrochemical reaction mechanisms should be probed carefully by both theoretical and experimental studies based on advanced *in situ* techniques, such as X-ray absorption spectroscopy (XAS), IR, Raman, and Mössbauer spectroscopy. Such studies would lead to the development of improved theoretical models that can fill the gap between experimentation and computation. Additionally, the emerging machine-learning technique would be beneficial for screening the possible composition, surface, and crystal structure of these materials for electrochemical applications, including the HER, OER, CO₂RR, and ORR. Finally, we hope that this review will accelerate investigations of the myriad combinations of TMD/MXene hybrids to realize the advent of next-generation energy-related technologies.

Conflicts of interest

There are no conflicts to declare.

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